Detecting Bands and Fermi Surfaces by State-of-the-Art ARPES

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Outline: Part I

State-of-the-Art ARPES: the essentials

Motivation and potential

- Formal description
 - One-step vs three-step model
 - The sudden approximation
 - Kinematics of photoemission
 - One-particle spectral function

Experimental

- State-of-art ARPES
- Surface vs bulk sensitivity

Summary and discussion

History of Photoemission

The Photoelectric Effect



- First experimental work performed by H. Hertz (1886), W. Hallwachs (1888), von Lenard (1900)
- Theoretical explanation by Einstein (1905)

FIRST EXPERIMENTAL EVIDENCE FOR QUANTIZATION OF LIGHT!

Is there anything else we can learn from the photoelectric effect?

Insights into the solid-state!

Many properties of a solids are determined by electrons near E_F (conductivity, magnetoresistance, superconductivity, magnetism)



Only a narrow energy slice around E_F is relevant for these properties (kT=25 meV at room temperature)

Allowed electronic states

Repeated-zone scheme



Interaction Effects between Electrons : "Many-body Physics"

Many-body effects are due to the interactions between the electrons and each other, or with other excitations inside the crystal :

1) A "many-body" problem : intrinsically hard to calculate and understand

2) Responsible for many surprising phenomena :

Superconductivity, Magnetism, Density Waves,







Angle-Resolved Photoemission Spectroscopy





ARPES: One-Step vs Three-Step Model

Photoemission Intensity $I(k,\omega)$ $w_{fi} \propto |\langle \Psi_f^N | \mathbf{A} \cdot \mathbf{p} | \Psi_i^N \rangle|^2 \delta(E_f^N - E_i^N - h\nu)$

One-step model





ARPES: One-Step vs Three-Step Model

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One-step model



Three-step model



ARPES: The Sudden Approximation

 $\begin{array}{l} \textbf{Photoemission} \\ \textbf{Intensity } I(\textbf{\textit{k}, \omega}) \end{array} \} \ w_{fi} \propto |\langle \phi_f^{\mathbf{k}} | \mathbf{A} \cdot \mathbf{p} | \phi_i^{\mathbf{k}} \rangle \langle \Psi_m^{N-1} | \Psi_i^{N-1} \rangle |^2 \delta(\omega - h\nu) \end{array}$



ARPES: Role of the Crystal Potential

 $\begin{array}{l} \textbf{Photoemission} \\ \textbf{Intensity } I(\textbf{k,\omega}) \end{array} \} \ w_{fi} \propto |\langle \phi_f^{\mathbf{k}} | \underline{\mathbf{A} \cdot \nabla V} | \phi_i^{\mathbf{k}} \rangle \langle \Psi_m^{N-1} | \Psi_i^{N-1} \rangle |^2 \delta(\omega - h\nu) \end{array}$



ARPES: Inner Potential and Determination of k_z

Free-electron final state
$$E_f(\mathbf{k}) = \frac{\hbar^2 \mathbf{k}^2}{2m} - |E_0| = \frac{\hbar^2 (\mathbf{k}_{\parallel}^2 + \mathbf{k}_{\perp}^2)}{2m} - |E_0|$$

because

 $\hbar^2 \mathbf{k}_{\parallel}^2 / 2m = E_{kin} \sin^2 \vartheta \qquad E_f = E_{kin} + \phi \qquad V_0 = |E_0| + \phi$

$$\mathbf{k}_{\perp} = \frac{1}{\hbar} \sqrt{2m(E_{kin} \cos^2 \vartheta + V_0)}$$



ARPES: FWHM and Inverse Lifetime

FWHM of an ARPES peak ∫

$$\Gamma = \frac{\frac{\Gamma_i}{|v_{i\perp}|} + \frac{\Gamma_f}{|v_{f\perp}|}}{\left|\frac{1}{v_{i\perp}} \left[1 - \frac{mv_{i\parallel}\sin^2\vartheta}{\hbar k_{\parallel}}\right] - \frac{1}{v_{f\perp}} \left[1 - \frac{mv_{f\parallel}\sin^2\vartheta}{\hbar k_{\parallel}}\right]\right|}$$



1) if
$$E_i \simeq E_F$$

 $\rightarrow \Gamma_i \longrightarrow 0 \rightarrow \Gamma \propto \Gamma_f$
2) if $|v_{i\perp}| \simeq 0$
 $\rightarrow \Gamma = \frac{\Gamma_i}{\left|1 - \frac{m v_{i\parallel} \sin^2 \vartheta}{\hbar k_{\parallel}}\right|} \equiv C \Gamma_i$
if $v_{i\parallel} < 0$, large; θ large; k_{\parallel} small
 $\rightarrow C < 1$, and $\Gamma < \Gamma_i$

ARPES: Energetics and Kinematics





ARPES: Energetics and Kinematics



Electrons in **Reciprocal Space k**_F E_F E_{R} K $\boldsymbol{E}_{\boldsymbol{F}}$

ARPES: Interacting Systems



Photoemission intensity: $I(\mathbf{k}, E_{kin}) = \sum_{f,i} w_{f,i}$

$$\begin{split} I(\mathbf{k}, E_{kin}) &\propto \sum_{f,i} |M_{f,i}^{\mathbf{k}}|^2 \sum_m |c_{m,i}|^2 \delta(E_{kin} + E_m^{N-1} - E_i^N - h\nu) \\ |M_{f,i}^{\mathbf{k}}|^2 &\equiv |\langle \phi_f^{\mathbf{k}} | \mathbf{A} \cdot \mathbf{p} | \phi_i^{\mathbf{k}} \rangle|^2 \qquad |c_{m,i}|^2 = |\langle \Psi_m^{N-1} | \Psi_i^{N-1} \rangle|^2 \end{split}$$

In general $\Psi_i^{N-1} = c_{\mathbf{k}} \Psi_i^N$ NOT orthogonal Ψ_m^{N-1}

ARPES: The One-Particle Spectral Function



Photoemission intensity: $I(k,\omega)=I_{\theta}|M(k,\omega)|^{2}f(\omega) A(k,\omega)$

Single-particle spectral function

$$A(\mathbf{k}, \omega) = -\frac{1}{\pi} \frac{\Sigma''(\mathbf{k}, \omega)}{[\omega - \epsilon_{\mathbf{k}} - \Sigma'(\mathbf{k}, \omega)]^2 + [\Sigma''(\mathbf{k}, \omega)]^2}$$

 $\Sigma(k,\omega)$: the "self-energy" captures the effects of interactions

Angle-Resolved Photoemission Spectroscopy



Parallel multi-angle recording

- Improved energy resolution
- Improved momentum resolution
- Improved data-acquisition efficiency

	∆E (meV)	$\Delta heta$
past	20-40	2°
now	2-10	<i>0.2</i> °



SSRL Beamline 5-4 : NIM / Scienta System

STANFORD SYNCHROTRON RADIATION LABORATORY



• High resolution

ΔE (meV)	$\Delta heta$
2-10	0.2°

- Ultra-high vacuum (~ 10⁻¹¹ torr)
- High angular precision (+/- 0.1°)
- Low base temperature (< 10 K)
- Wide temperature range (10-350 K)
- Variable photon energies (12-30 eV)
- Multiple light sources (He lamp)
- Control of light polarization
- Single crystal cleaving tools
- Sample surface preparation & cleaning
- Low-Energy Electron Diffraction (LEED)



ARPES: Surface vs Bulk Sensitivity

Mean-free path for excited electrons





Sekiyama et al., Nature 403, 396 (2000)

ARPES: Surface vs Bulk Sensitivity

Mean-free path for excited electrons





Sekiyama et al., Nature 403, 396 (2000)

ARPES on 1D Nanostructures: Spin-Charge Separation?

C. Kim et al., PRL 77, 4054 (1996)





ARPES: Advantages and Limitations

Advantages

- Direct information about the electronic states!
- Straightforward comparison with theory little or no modeling.
- High-resolution information about
 BOTH energy and momentum
- Surface-sensitive probe
- Sensitive to "many-body" effects
- Can be applied to small samples (100 μm x 100 μm x 10 nm)

Limitations



- Not bulk sensitive
- Requires clean, atomically flat surfaces in **ultra-high vacuum**
- Cannot be studied as a function of pressure or magnetic field

Outline: Part II

Electronic structure of complex systems

$\blacktriangleright 2H-NbSe_2 - Sr_2RuO_4$

- Detecting bands and Fermi surface
- Bulk & surface electronic structure

► Nb - $Bi_2Sr_2CaCu_2O_{8+\delta}$

- Superconducting gap: s-wave vs. d-wave
- Bogoliubov quasiparticles in high-T_c cuprates
- Be(0001) Mo(110) Bi₂Sr₂CaCu₂O_{8+δ}
 - Many-body effects in the quasiparticle dispersion
- Conclusions and discussion

2H-NbSe₂: Normal State Electronic Structure



Sr₂RuO₄: basic properties

2D perovskite



Unconventional superconductivity

- Pairing mechanism?
- Order parameter?
- FM-AF fluctuations ?

Rice & Sigrist, JPCM 7, L643 (1995)





Lattice-magnetism interplay Orbital degrees of freedom

- Sr_2RuO_4 : 2D Fermi Liquid (ρ_c/ρ_{ab} =850)
- Ca₂RuO₄: insulating Anti-FerroMagnet
- **SrRuO₃** : metallic **FerroMagnet**

Low-Energy Electronic structure of Sr₂RuO₄



 $\blacktriangleright \text{ Band structure calculation: } \mathbf{3} \mathbf{t}_{2g} \text{ bands crossing } \mathbf{E}_{\mathsf{F}} \\ \blacksquare 3 \text{ sheets of FS} \begin{cases} \alpha \text{ (hole-like)} \\ \beta \text{ and } \gamma \text{ (electron-like)} \end{cases}$





Fermi Surface Topology of Sr₂RuO₄

Early ARPES results gave a different topology

de Haas-van Alphen



A.P. Mackenzie *et al.*, PRL **76**, 3786 (1996) C. Bergemann *et al.*, PRL **84**, 2662 (2000)





I.I. Mazin *et al.*, PRL **79**, 733 (1997)

T.Yokoya *et al.*, PRB **54**, 13311 (1996) D.H. Lu *et al.*, PRL **76**, 4845 (1996)

ARPES: additional information dHvA: limited set of systems

Fermi Surface Topology of Sr₂RuO₄



ARPES Spectra

Χ

Fermi Surface Topology of Sr₂RuO₄



A. Damascelli et al., PRL 85, 5194 (2000)

Surface instability

0.2 0.0

Binding Energy (eV)

Band folding

Х

Surface reconstruction of cleaved Sr₂RuO₄



R. Matzdorf et al., Science 289, 746 (2000)



Rotation of the RuO₆ octahedra around the c axis (9°)

Surface electronic structure of Sr₂RuO₄

On samples cleaved at 180 K the surface-related features are suppressed

Cold cleave Hot cleave E_F mapping ±10 meV T=10 K **T=180 K** 100 100 100 100 0 0 0 Binding energy (meV) Binding energy (meV)

A. Damascelli *et al.*, PRL **85**, 5194 (2000); K.M. Shen, A. Damascelli, *et al.*, PRB **64**, 180502(R) (2001)

Bulk electronic structure of Sr₂RuO₄

What do we learn about the bulk electronic structure?

- Fermi Surface
- Fermi velocity
- Effective mass



I.I. Mazin et al., PRL 79, 733 (1997)



A. Damascelli et al., PRL 85, 5194 (2000)

Dispersion of the bulk electronic bands



Experiment compares well with LDA+U calculations

A. Damascelli *et al.*, PRL **85**, 5194 (2000) A. Liebsch & A. Lichtenstein, PRL **84**, 1591 (2000)

Superconductivity







"Classic Low-temperature" Superconductors



Superconductivity can only be seen on low energy scales and needs high resolution!



"Classic Low-temperature" Superconductors



Superconductivity can only be seen on low energy scales and needs high resolution!



Binding energy (meV)

High-Temperature Superconductors: Bi2212

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PHYSICAL REVIEW LETTERS

8 MARCH 1993

Anomalously Large Gap Anisotropy in the *a-b* Plane of Bi₂Sr₂CaCu₂O_{8+δ}

Z.-X. Shen,^{(1),(2)} D. S. Dessau,^{(1),(2)} B. O. Wells,^{(1),(2),(a)} D. M. King,⁽²⁾ W. E. Spicer,⁽²⁾ A. J. Arko,⁽³⁾ D. Marshall,⁽²⁾ L. W. Lombardo,⁽¹⁾ A. Kapitulnik,⁽¹⁾ P. Dickinson,⁽¹⁾ S. Doniach,⁽¹⁾ J. DiCarlo,^{(1),(2)} A. G. Loeser,^{(1),(2)} and C. H. Park^{(1),(2)}

Courtesy of Kyle Shen

High-T_c Superconductors: s-wave vs. d-wave gap

High-T_c Superconductors: Bogoliubov QP in Bi2223

$$A_{\rm BCS}(k,\,\omega) = \frac{1}{\pi} \left\{ \frac{|u_k|^2 \Gamma}{(\omega - E_k)^2 + \Gamma^2} + \frac{|v_k|^2 \Gamma}{(\omega + E_k)^2 + \Gamma^2} \right\}$$

Matsui *et al.*, PRL **90**, 217002 (2003)

Many-Body effects: Electron-Phonon Coupling

Eschrig, Norman, PRB 67, 144503 (2003)

Hengsberger et al., PRL 83, 592 (1999)

Valla et al., PRL 83, 2085 (1999)

Many-Body effects in the High-T_c Cuprates

Valla et al., Science 285, 2110 (1999)

Mechanism for High-T_c { Magnetic fluctuations ? Electron-phonon coupling ?

Many Body effects in the Quasiparticle Dispersion

Lanzara et al., Nature 412, 510

Electron Momentum

Mechanism for High-T_c { Magnetic fluctuations ? Electron-phonon coupling ?

Conclusions

ARPES results from complex systems

- Bands and FS in unprecedented detail
- Fermi velocity and effective mass
- Superconducting (d-wave) gap
- Many-body effects in the QP dispersion
- Nanostructured materials (surface FM)

ARPES is a **powerful tool** for the study of the electronic structure of complex systems

For a review article see:

A. Damascelli, Z. Hussain, and Z.-X Shen, Rev. Mod. Phys. 75, 473 (2003)

For additional material see:

http://www.physics.ubc.ca/~damascel/

